RMDXS SERIES

MINIATURE SINGLE-PHASE SURFACE MOUNT BRIDGE RECTIFIER

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RMD1S THRU RMD7S

MINIATURE GLASS PASSIVATED FAST RECOVERY SINGLE-PHASE SURFACE MOUNT BRIDGE RECTIFIER



REVERSE VOLTAGE: FORWARD CURRENT:

50 to 1000 VOLTS 0.5 AMPERE

FEATURES

- · Glass passivated chip junction
- · Fast recovery time, low switching loss
- · High surge overload rating of 25 Amperes peak
- · Ideal for printed circuit board
- \cdot High temperature soldering guaranteed:

260°C for 10 seconds

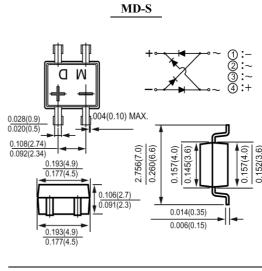
MECHANICAL DATA

Case: Molded plastic, MD-S

Epoxy: UL 94V-O rate flame retardant

Terminals: Leads solderable per MIL-STD-202,

method 208 guaranteed Mounting position: Any Weight: 0.008ounce, 0.22gram



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25 ambient temperature unless otherwise specified.

Single phase, half wave, $60H_Z$, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	RMD1S	RMD2S	RMD3S	RMD4S	RMD5S	RMD6S	RMD7S	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current			•	•		•		•	
(see Fig. 1) on glass-epoxy P.C.B (Note 2)	$I_{(AV)}$ 0.5								Amp
on aluminum substrate (Note 3)	0.8								
Peak Forward Surge Current,									
8.3ms single half-sine-wave	I_{FSM} 25							Amp	
superimposed on rated load (JEDEC method)									
Maximum Forward Voltage	V	1.25							Volts
at 0.4A DC and 25	V_{F}								
Maximum Reverse Current at T _A =25	т.	5.0 500							uAmp
at Rated DC Blocking Voltage T _A =125	I_R								
Typical Junction Capacitance (Note 1)	C_{J}	13							pF
Maximum Reverse Recovery Time (Note 4)	T_{RR}		1:	50		250	50	00	nS
Typical Thermal Resistance (Note 3)	$R_{\theta JA}$	70						/W	
Typical Thermal Resistance (Note 2)	$R_{\theta JL}$	20							/W
Operating and Storage Temperature Range	T _J , Tstg	-55 to +150							

NOTES:

- 1- Measured at 1 $\ensuremath{\text{MH}_{\text{Z}}}$ and applied reverse voltage of 4.0 VDC.
- 2- On glass epoxy P.C.B. mounted on 0.05 x 0.05" (1.3 x 1.3mm) pads
- 3- On aluminum substrate P.C.B. with an area of 0.8" x 0.8" (20 x 20mm) mounted on 0.05 x 0.05" (1.3 x 1.3mm) solder pad
- 4- Reverse Recovery Test Conditions: I_F =.5A , I_R =1A , I_{RR} =.25A.



RATINGS AND CHARACTERISTIC CURVES

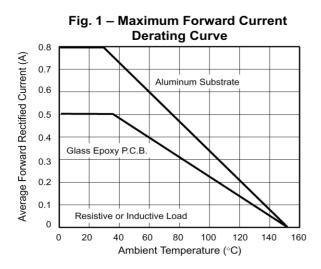


Fig. 2 - Maximum Non-Repetitive Peak **Forward Surge Current** 35 T_A = 40°C Peak Forward Surge Current (A) 30 Single Half Sine-Wave (JEDEC Method) 25 20 f = 60Hz 15 10 5.0 0 100 Number of Cycles

